



DMMT3906W

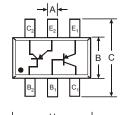
MATCHED PNP SMALL SIGNAL SURFACE MOUNT TRANSISTOR

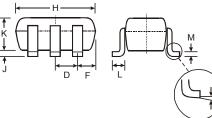
Features

- Epitaxial Planar Die Construction
- Intrinsically Matched PNP Pair (Note 1)
- Small Surface Mount Package
- 2% Matched Tolerance, hFE, VCE(SAT), VBE(SAT)
- Lead Free/RoHS Compliant (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4 and 5)

Mechanical Data

- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: K4B, See Page 4
- Ordering & Date Code Information: See Page 4
- Weight: 0.015 grams (approximate)





SOT-363									
Dim	Min	Max							
Α	0.10	0.30							
В	1.15	1.35							
С	2.00	2.20							
D	0.65 N	lominal							
F	0.30	0.40							
Н	1.80	2.20							
J	_	0.10							
K	0.90	1.00							
L	0.25	0.40							
M	M 0.10								
α 0° 8°									
All Dimensions in mm									

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Collector-Base Voltage		V_{CBO}	-40	V
Collector-Emitter Voltage		V_{CEO}	-40	V
Emitter-Base Voltage		V_{EBO}	-5.0	V
Collector Current - Continuous		Ic	-200	mA
Power Dissipation	(Note 3)	P _d	200	mW
Thermal Resistance, Junction to Ambient	(Note 3)	$R_{ heta JA}$	625	°C/W
Operating and Storage Temperature Range		T _j , T _{STG}	-55 to +150	°C

Notes:

- Built with adjacent die from a single wafer.
- No purposefully added lead.
- Device mounted on FR5 PCB: 1.0 x 0.75 x 0.62 in.; pad layout as shown on suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.



Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition				
OFF CHARACTERISTICS (Note 6)									
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-40	_	V	$I_C = -10\mu A, I_E = 0$				
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	-40	_	V	I _C = -1.0mA, I _B = 0				
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5.0	_	V	$I_E = -10\mu A, I_C = 0$				
Collector Cutoff Current	I _{CEX}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$				
Base Cutoff Current	I _{BL}		-50	nA	$V_{CE} = -30V, V_{EB(OFF)} = -3.0V$				
ON CHARACTERISTICS (Note 6)				•					
DC Current Gain (Note 7)	h _{FE}	60 80 100 60 30	300 —	_	$\begin{split} I_C &= -100 \mu A, V_{CE} = -1.0 V \\ I_C &= -1.0 m A, V_{CE} = -1.0 V \\ I_C &= -10 m A, V_{CE} = -1.0 V \\ I_C &= -50 m A, V_{CE} = -1.0 V \\ I_C &= -100 m A, V_{CE} = -1.0 V \end{split}$				
Collector-Emitter Saturation Voltage (Note 7	V _{CE(SAT)}		-0.25 -0.40	V	I_C = -10mA, I_B = -1.0mA I_C = -50mA, I_B = -5.0mA				
Base-Emitter Saturation Voltage (Note 7	V _{BE(SAT)}	-0.65 —	-0.85 -0.95	V	I_C = -10mA, I_B = -1.0mA I_C = -50mA, I_B = -5.0mA				
Base-Emitter Voltage Matching	ΔV_{BE}		-1	mV	$V_{CE} = -5V$, $I_C = -2mA$				
SMALL SIGNAL CHARACTERISTICS									
Output Capacitance	C _{obo}	_	4.5	pF	$V_{CB} = -5.0V$, $f = 1.0MHz$, $I_E = 0$				
Input Capacitance	C_{ibo}		10	pF	$V_{EB} = -0.5V$, $f = 1.0MHz$, $I_C = 0$				
Input Impedance	h _{ie}	2.0	12	kΩ					
Voltage Feedback Ratio	h _{re}	0.1	10	x 10 ⁻⁴	V _{CE} = 10V, I _C = 1.0mA,				
Small Signal Current Gain	h _{fe}	100	400	_	f = 1.0kHz				
Output Admittance	h _{oe}	3.0	60	μS					
Current Gain-Bandwidth Product	f _T	250	_	MHz	V_{CE} = -20V, I_{C} = -10mA, f = 100MHz				
Noise Figure	NF		4.0	dB	V_{CE} = -5.0V, I_{C} = -100 μ A, R_{S} = 1.0k Ω , f = 1.0kHz				
SWITCHING CHARACTERISTICS									
Delay Time	t _d		35	ns	$V_{CC} = -3.0V, I_{C} = -10mA,$				
Rise Time	t _r	_	35	ns	$V_{BE(off)} = 0.5V, I_{B1} = -1.0mA$				
Storage Time	ts		225	ns	V _{CC} = -3.0V, I _C = -10mA,				
Fall Time	t _f		75	ns	$I_{B1} = I_{B2} = -1.0 \text{mA}$				

Notes:

Short duration pulse test used to minimize self-heating effect. The DC current gain, h_{FE} , (matched at I_C = -10mA and V_{CE} = -1.0V) Collector Emitter Saturation Voltage, $V_{CE(SAT)}$, and Base Emitter Saturation Voltage, $V_{BE(SAT)}$ are matched with typical matched tolerances of 1% and maximum of 2%.



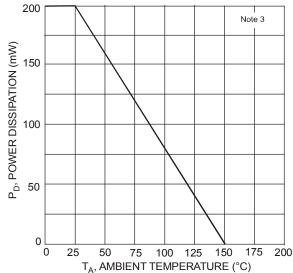
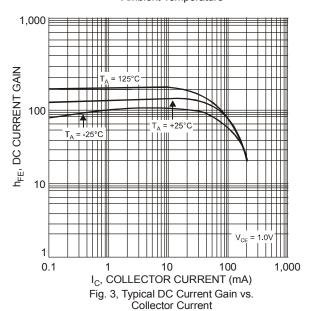
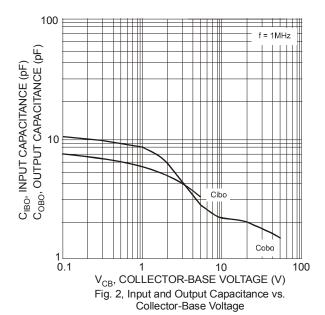


Fig. 1, Max Power Dissipation vs. Ambient Temperature



1.0 V_{BE(SAT)}, BASE-EMITTER SATURATION VOLTAGE (V) 0.9 8.0 0.7 0.6 0.5 10 100 I_C, COLLECTOR CURRENT (mA) Fig. 5, Typical Base-Emitter

Saturation Voltage vs. Collector Current



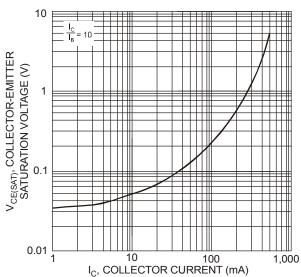


Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

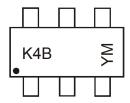


Ordering Information (Note 8)

Device	Packaging	Shipping		
DMMT3906W-7-F	SOT-363	3000/Tape & Reel		

Notes: 8. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



K4B = Product Type Marking Code YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

	_	_						_			
Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	N	Р	R	S	Т	U	V	W	Х	Υ	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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